## Abstract Submitted for the MAR16 Meeting of The American Physical Society

Charge transfer effect of FeSe thin films on  $SrTiO_3^1$  YUANJUN ZHOU, ANDREW MILLIS, Columbia University — Monolayer FeSe grown on  $SrTiO_3$  substrate has shown a significant enhancement in the superconducting transition temperature ( $T_c$ ) relative to the bulk material. Monolayers of FeSe are electron doped relative to bulk; we propose that the doping comes from work-function-mismatch driven charge transfer from  $SrTiO_3$  impurity bands, modified by out-of-plane polar distortions of the  $SrTiO_3$ . We present a modified Schottky model combined with density functional calculations substantiating this picture for monolyaer FeSe films on Nb doped  $SrTiO_3$ . Physically relevant levels of Nb doping are shown to lead to doping of the FeSe compatible with observation. Adding polar fluctuations to the model leads to an electron-phonon interaction whose effect on the transition temperature is investigated.

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